
	<h2>SI8401DB-T1-E3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI8401DB-T1-E3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 20V 3.6A 2X2 4-MFP</p> <p><b>Datenblätter:</b>  <a href="#">SI8401DB-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 50825 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SI8401DB-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 3.6A 2X2 4-MFP
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	50825 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	4-XFBGA, CSPBGA
Supplier Device-Gehäuse	4-Microfoot
Verlustleistung (max)	1.47W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.6A (Ta)
Rds On (Max) @ Id, Vgs	65 mOhm @ 1A, 4.5V
VGS (th) (Max) @ Id	1.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI8401DB-T1-E3 ist neu im Original, Suche SI8401DB-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI8401DB-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI8401DB-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI8401DB-T1-E1</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 3.6A 2X2 4-MFP</p>	 <p><b>SI8401AB-B-ISR</b> Energy Micro (Silicon Labs) DGTL ISO 2.5KV 2CH I2C 8SOIC</p>	 <p><b>SI8402</b> SILICON SILICON WB SOIC</p>	 <p><b>SI8402DB-T1</b> VISHAY SI8402DB-T1 VISHAY</p>
 <p><b>SI8402AB-B-ISR</b> Energy Micro (Silicon Labs) DGTL ISO 2.5KV 2CH I2C 8SOIC</p>	 <p><b>SI8401AB-B-IS</b> Energy Micro (Silicon Labs) DGTL ISO 2.5KV 2CH I2C 8SOIC</p>	 <p><b>SI8401DB-T1</b> SILICON SI8401DB-T1 SILICON</p>	 <p><b>SI8401DB-T1-E1</b> Vishay / Siliconix MOSFET P-CH 20V 3.6A 2X2 4-MFP</p>

### heiße Teile

Mehr

 SI8234AB-C-IS1	 SI8234AD-C-ISR	 SI8235BB-C-IS	 SI8235BD-D-ISR	 SI8236BB-C-IM
 SI8238AD-D-ISR	 SI8252-IMR	 SI8261AAC-C-IS	 SI8261ABD-C-IS	 SI8261ACC-C-IS
 SI8261BAC-C-IPR	 SI8261BAC-C-IS	 SI8261BAD-C-IS	 SI8261BBC-C-IS	 SI8261BBD-C-IS
 SI8261BCC-C-IP	 SI8261BCC-C-IS	 SI8261BCD-C-IS	 SI8388P-IU	 SI8400AA-B-IS
 SI8400AB-B-ISR	 SI8401DB-T1	 SI8401DB-T1-E1	 SI8401DB-T1-E1	 SI8401DB-T1-E3
 SI8402DB-T1	 SI8402DB-T1-E1	 SI8402DB-T1-E1	 SI8402DB-T1-E1	 SI8402DB-T1-E3
 SI8404DB-T1-E1	 SI8404DB-T1-E1	 SI8405DB	 SI8405DB-T1	 SI8405DB-T1-E1
 SI8405DB-T1-E1	 SI8405DB-T1-E3	 SI8405DB-T1-E3	 SI8409DB-T1	 SI8409DB-T1-E1
 SI8409DB-T1-E1	 SI8410AB	 SI8410BB-D-ISR	 SI8410BB-I-DS	 SI8413DB-T1-E1
 SI8413DB-T1-E1	 SI8415DB-T1	 SI8415DB-T1-E1	 SI8415DB-T1-E1	 SI8417DB-T2-E1

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